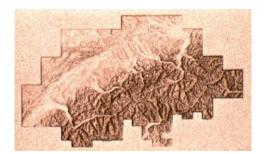
SWISSLASER * NET Annual meeting Burgdorf

Precision Cold Ablation Material Processing using High-Power Picosecond Lasers



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26 November 2009

Background of Time-Bandwidth Products

- First product sales end of 1996, organically grown (no outside investors)
- Spin-off of ETH Zurich "SESAM[®]" know-how
- Strong technical staff (Ph.D. & masters level) focused on laser production
- Headquartered at Technopark Zurich
- International network of sale representatives/distributors in all key markets
- Industrial customers in semiconductor, biotech, material processing, etc.
- Products established as reliable in "24-7" operation – for either R&D or industrial applications









TBP product range

OEM & Customized Lasers



Flexible, modular set of product platforms Customizable for scientific or industrial applications Broad set of performance parameters

Pulse durations	<50 fs to >500 ps
Wavelengths	260 nm – 1550 nm
Output power	<1 W to >50 W
Pulse energies	up to 1 mJ
Repetition rates	single shot to >10 GHz



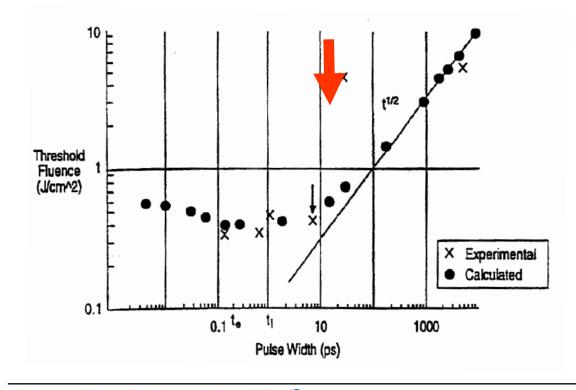




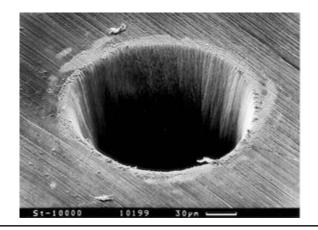
Material processing: "long" versus "short" pulses

Picosecond pulses can cut through "anything" with a very low amount of heating / residual damage

"Cold ablation" starts at around 10 ps pulsewidth



Why? Peak Power required to start ablation is reached at lower pulse energy with shorter pulses



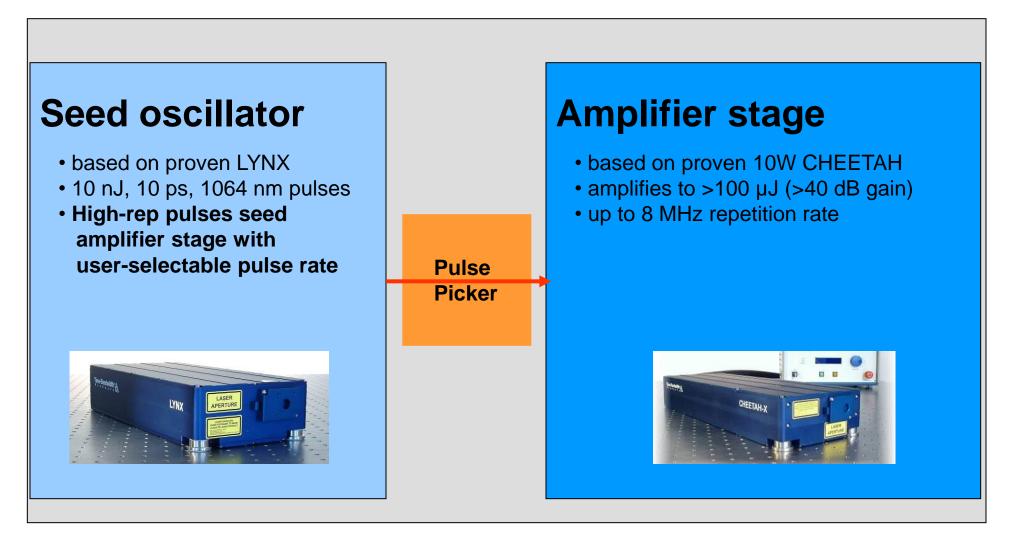
Why picoseconds?

- Substantial process advantages compared to nanosecond pulses for micromachining
 - -smaller heat-affected zone (less than 1 micron typical)
 - -less micro-cracking
 - -less recast
 - -with substantially faster speed / productivity (depending on process)
 - -higher quality \leftrightarrow higher speed \leftrightarrow (lower cost)
- Substantial system advantages compared to femtosecond pulses
 - -system much less complex and lower costs
 - -dispersion of picosecond pulses not an issue
 - -system components more proven in industrial environments
 - -power scaling currently possible for increased process speeds
 - "Most of the advantages of femtosecond lasers but much simpler / scalable"
 - -Femtosecond systems more applicable for "2-photon" processes

Time-Bandwidth®

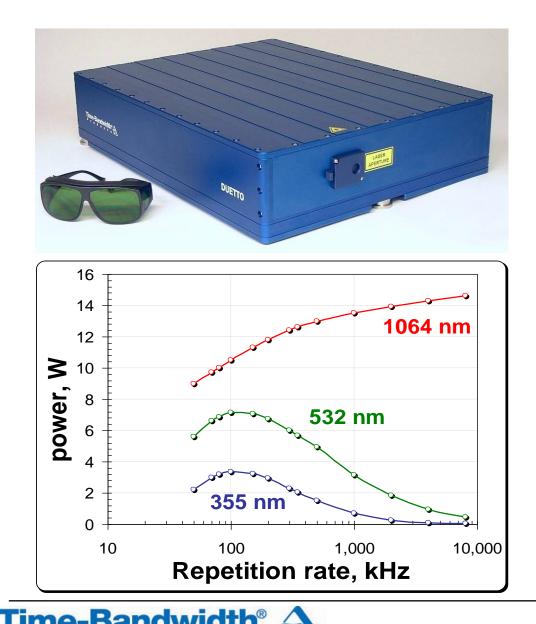
DUETTOTM - Integrated Industrial MOPA

Master Oscillator Power Amplifier diode-pumped picosecond laser system





DUETTO - key performance parameters

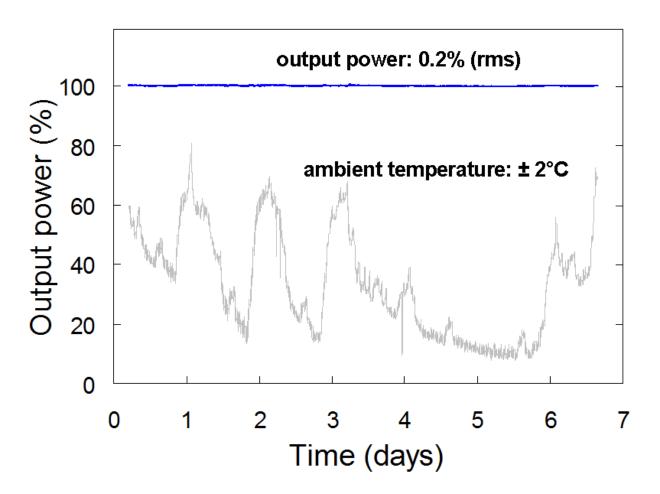


output power repetition rate pulse energy pulse width peak power wavelength M² (TEM₀₀)

> 10 W
50 kHz - 8 MHz
up to 200 µJ
10 ps
up to 20 MW
1064 nm
< 1.3

DUETTO – excellent long-term stability characteristics







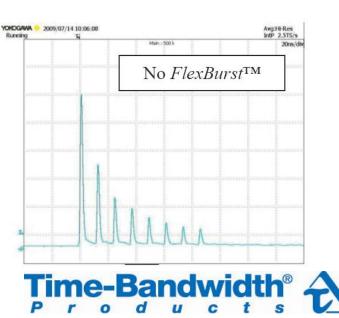
DUETTO - modular customizable options

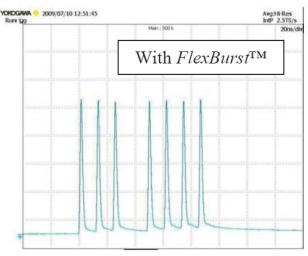
- Power scalable with booster amplifier
 - FUEGO optional power booster to >50W average power
- Frequency Conversion
 - to 532 nm (green): >60% conversion efficiency
 - to 355 nm (UV): >30% conversion efficiency
 - to 266 nm or other wavelengths also available
- Pulse on demand POD
 - Individually triggerable pulses single-shot to MHz regime
 - or arbitrary groups of pulses
 - avoids typical pre-pulse or first-pulse overshoot often seen in other systems
 - FlexBurst[™] technology (next slide)
- Other options
 - timing synchronization to external clock with sub-picosecond accuracy
 - variable (switchable) pulsewidths
 - repetition rate at oscillator output (80 MHz typical)

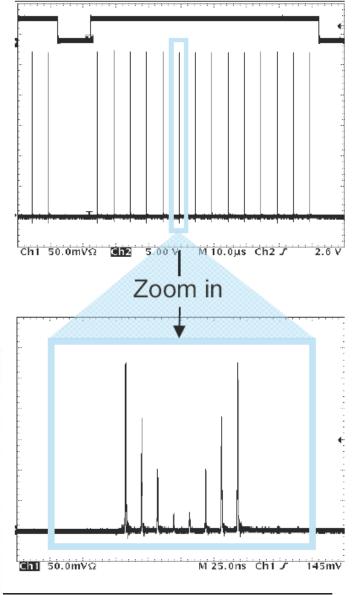


FlexBurst[™] technology

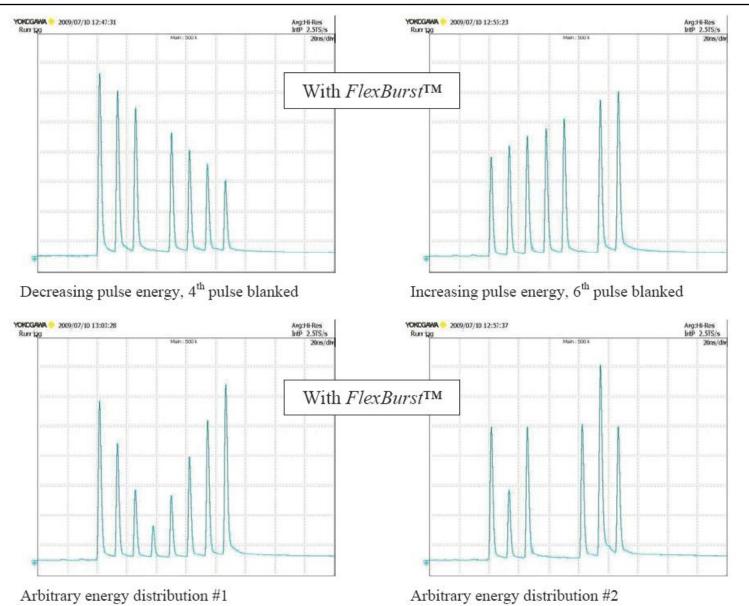
- Generation of <u>arbitrary</u> bursts of pulses
- Frequency of bursts adjustable
- Time between pulses within burst: ca 12 ns
- Number of pulses adjustable
- Amplitude of each <u>individual</u> pulse adjustable
- NO first pulse problem
- \Rightarrow Current research activities show that burst mode can
 - significantly increase the ablation rate
 - improve surface quality





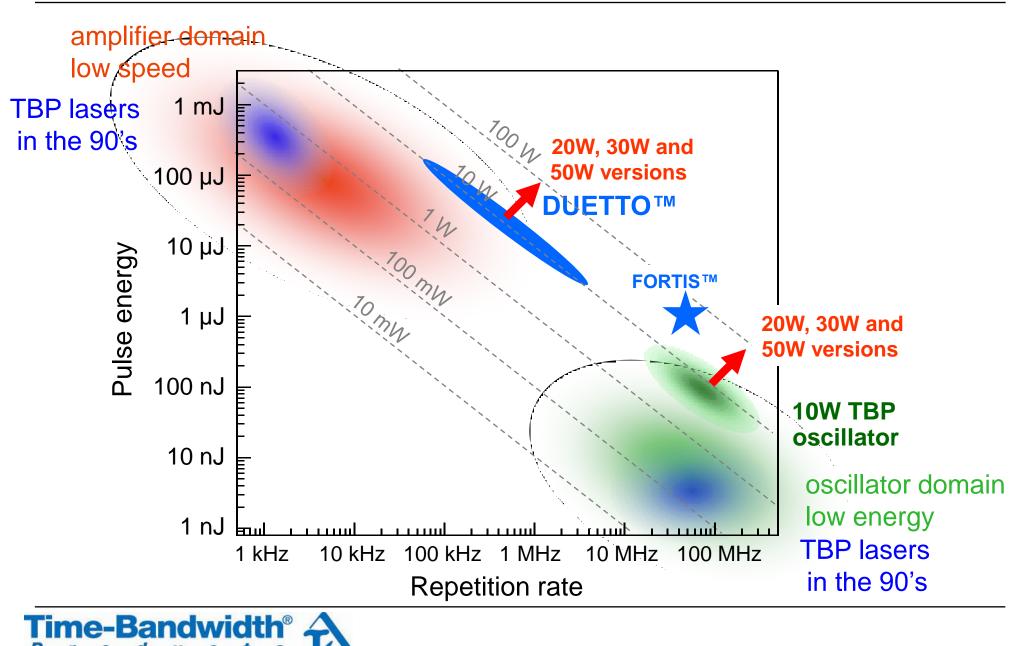


FlexBurst technology: example patterns



Time-Bandwidth®

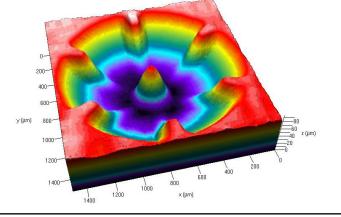
Power scaling with both high power and pulse energy



Power amp - high average power & high pulse energy

High Pulse Energy Laser Products Duetto (amp) Fuego or power amplifier or **Cheetah (oscillator)** Argos DUETTO[™] laser model FUEGO[™] laser model ARGOS[™] laser model MOPA MOPA oscillator Type: 50 kHz – 8 MHz 200 kHz – 8 MHz 50 MHz to 200 MHz Repetition rate: 1064 nm 1064 nm 1064 nm Fundamental wavelength: 12 ps or longer Pulse width: 12 ps or longer 12 ps or longer Output power: ≥ 10W 20W, 30W or ≥45W 20W, 30W or ≥45W





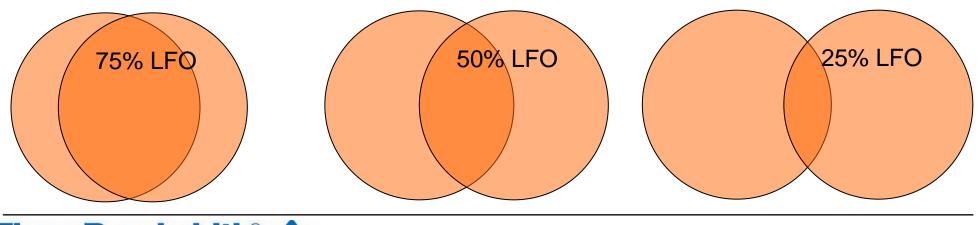
Picosecond Micromachining Guidelines

- Energy density required for ablation typically 1 Joule / cm²
- 10-100 nm layer removed per pulse: "gentle ablation"
- Top Hat beam profile can give ~35% more efficiency than Gaussian
- High repetition rates increase speed → limited by scanner speeds and "LFO" = Laser Focus Overlap: "speed limit" due to spot size overlap
- Thin films can benefit from high scan speeds (>>10 m/s) due to the high repetition rates possible (>1 MHz), but require precise scanner systems
- ~1 mm³ / minute for un-optimized process with 10W average power
- up to 10-50 mm³ / minute for optimized process with 50W average power
- Final speed limit <u>depends critically</u> on material, process parameters, and beam delivery limitations



Processing speed and pulse repetition rate

- Pulse repetition rate of the Duetto scales from 100 kHz to 8 MHz with virtually no change in pulse and beam parameters
 - as opposed to other approaches where pulse quality and stability degrades as repetition rate increases
- Single-pulse processes can benefit from higher pulse rate
- "Laser Focus Overlap" (LFO) sets upper speed limit on ablative (line) processes
- Small features require high pulse repetition rate to achieve high scan speed
- Example: spot size 10 µm, LFO 50%
 - -maximum scan speed of <u>1 m/s at 200 kHz</u>
 - -maximum scan speed of 10 m/s at 2 MHz





Applications

Metals

- very thin (thin-film)
- precision holes (sub-100 $\mu\text{m})$
- surface feature structuring / tribology
- Ceramics
 - precision cutting / structuring without cracking (resulting in low-yields)

Semiconductor / Photovoltaic

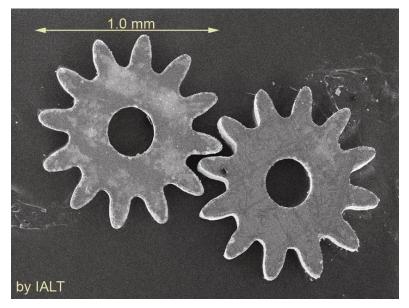
- hole / via drilling
- ablative processes / structures
- singulation

Dielectric

- structuring
- selective ablation
- hard dielectrics like sapphire and diamond
- glass welding
- "Mixed" materials
 - picosecond (IR or UV) can cleanly cut / ablate through combinations of the above materials
 - semiconductor: low-k coated chips
 - solar: thin-film technologies (CIGS, CdTe, etc)
 - medical: coated stents
 - etc, etc.

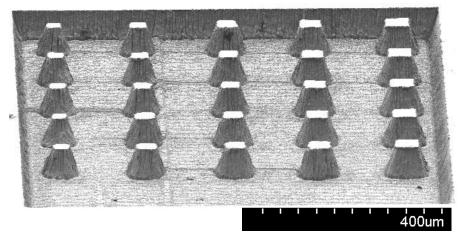


Application Examples of Duetto: Metals, Ceramic

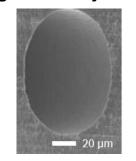


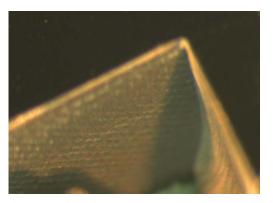
Miniature gears in 50 μm stainless steel foil

Columns ablated in copper



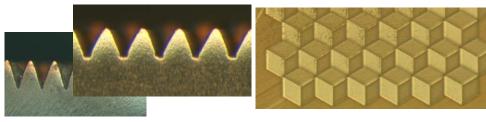
Sub-100 μm holes (e.g. diesel injectors)





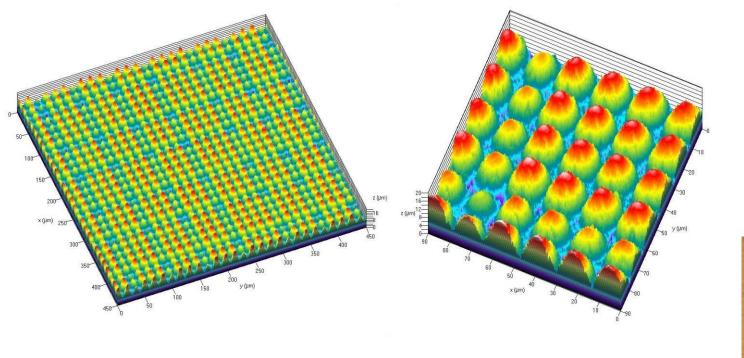
Ceramic micro-machining without cracking

Gears, teeth structures, patterns in metal



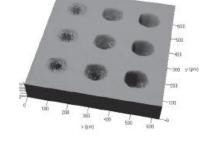


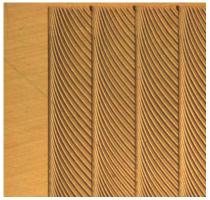
Application Examples of Duetto: Surfaces



Tribology: microstructuring of surface features

"Spikes" and "Dimples" on surfaces





surface patterning

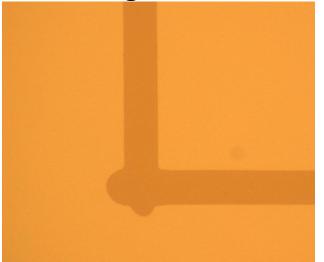


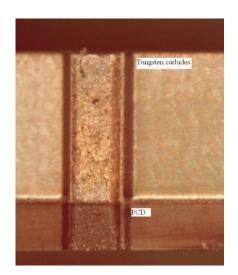
Application Examples of Duetto: Thin Films

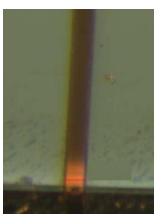
TCO on glass



TCO on organic substrate



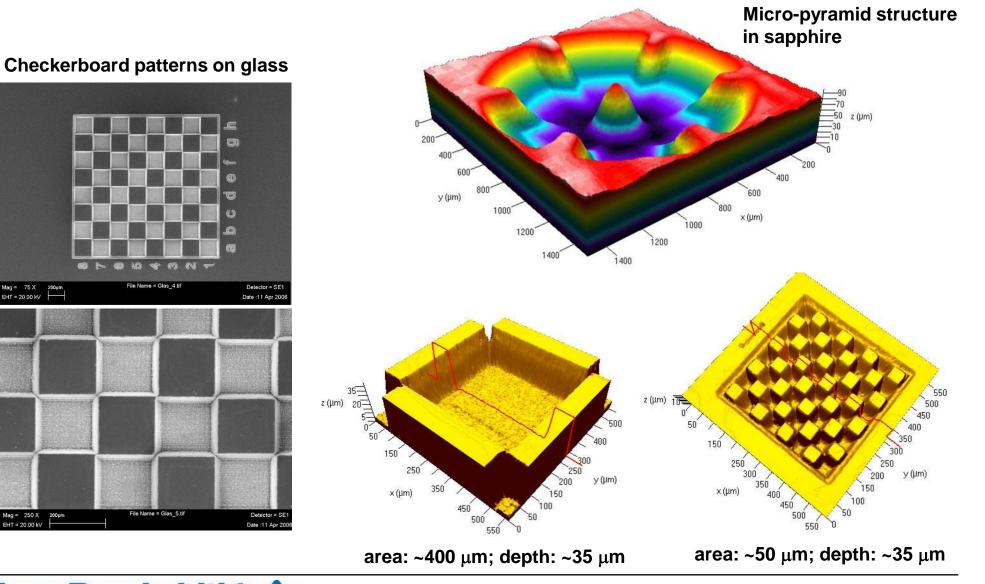




Metal layer on organic substrate



Application Examples: Transparent Materials



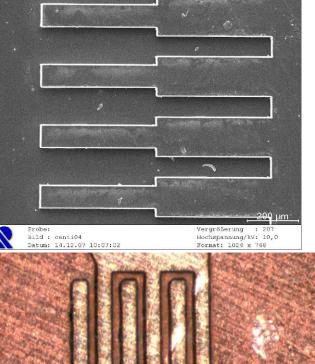
Pictures courtesy of IALT

Application Examples of Duetto: Plastics, Polymers

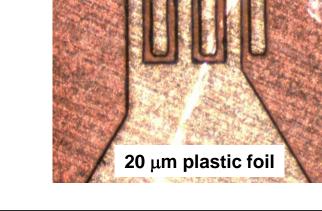


Precise selective ablation of layers on polymer substrate

Plastic cantilevers 20 µm thickness



Berner Fachhochschule
 Technik und Informatik
 Lasses, bies Euglin eing



400um



Application Examples of Duetto: Others

Berner Fachhochschule

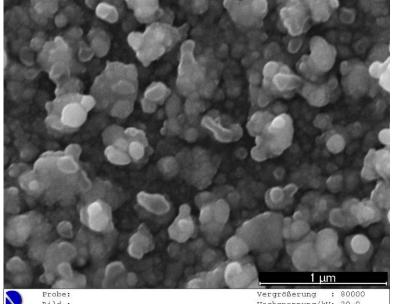
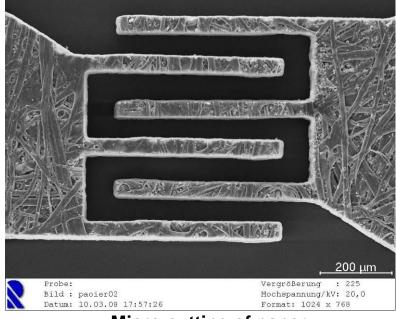


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Hochspannung/kV: 20,0 Format: 1024 x 768

Deposition of Nanoparticles (Laser Induced Plasma Assisted Ablation LIPAA)

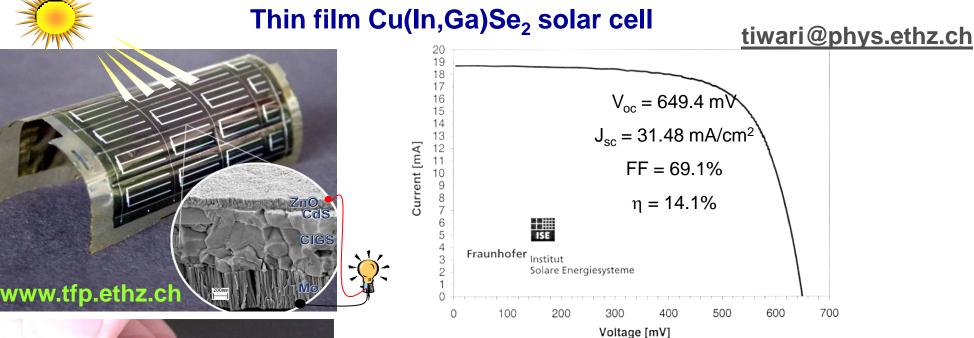


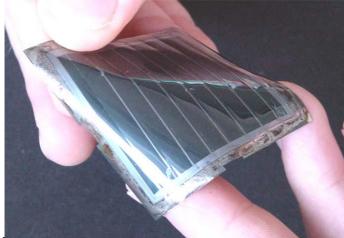
Micro-cutting of paper

(no residual burning / damage)



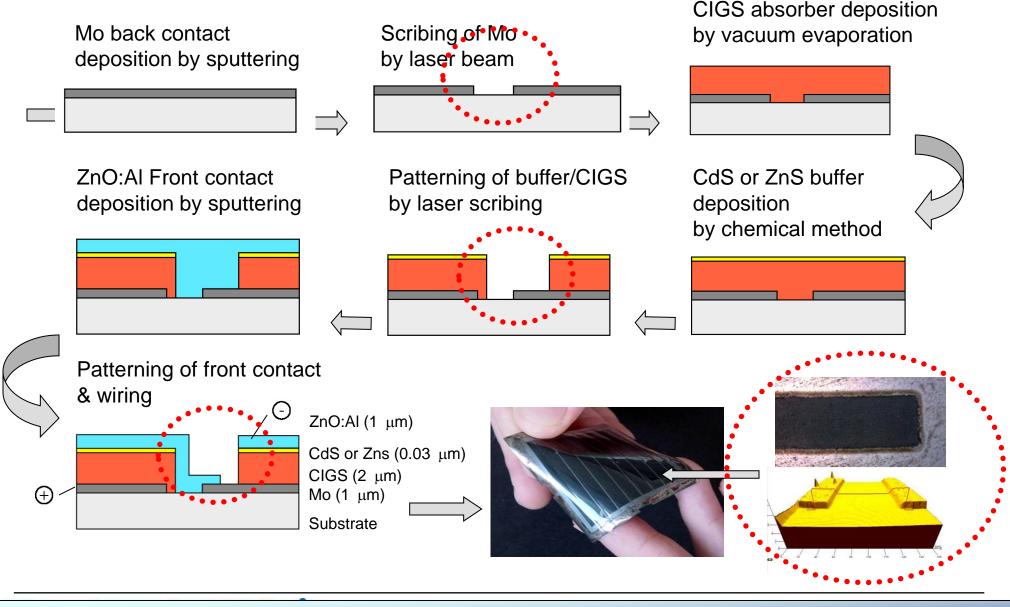
Lightweight and flexible solar cell on polyimide World record efficiency of 14.1%





- Multifunctional layers and heterostructures
 - Large area coatings with vacuum and chemical processes
- Laser scribing and patterning of structures
- Monolithically interconnected solar module

Monolithic interconnection in CIGS solar modules



Eidgenössische Technische Hochschule Zürich Swiss Federal Institute of Technology Zurich Thin Film Physics Group Laboratory for Solid State Physics

Summary

- Picosecond lasers offer improved quality, faster processing speed for "fine" ablation processes
- Duetto flexible, modular industrial picosecond system for micromachining
 - Broad repetition rate changing for process optimization
 - Wavelength flexibility (IR, green, UV)
 - High-power add-on modules
 - FlexBurst pulse control
- Thin-film, surface, microstructuring applications
 - Semiconductor, biotech, solar cell, security,



- Thanks for your attention!
- Man thanks to Professor Beat Neuenschwander and team from Laser Surface Engineering group at Applied Laser, Photonics and Surface Technologies, Bern University of Applied Sciences for all the application support!







Other applications

- Analysis
 - Wafer inspection, Multi-photon microscopy, CARS, FLIM
- Medical applications
 - Ophthalmology, Laser dissection
- Metrology
 - Optical clocking, Optical sampling, Laser ranging
- Optical communication
 - Special high-performance data transmission
- Wavelength conversion
 - Visible / UV wavelengths, optical parametric oscillators, THz generation
- High-Energy Physics
 - Photocathode illumination, EUV & X-ray generation

